3500V

2135A

20000A

**1500**μC

**6.5**μ**s** 



# **Fast Recovery Diode**

 $V_{RRM}$ 

F(AV)

I FSM

Supersedes September 1996 version, DS4219 - 2.3

DS4219 - 2.4 March 1998

**KEY PARAMETERS** 

#### **APPLICATIONS**

- Power Supplies.
- Freewheel Diode.
- Battery Chargers.
- D.C. Motor Control.
- Welding.
- Rectification.

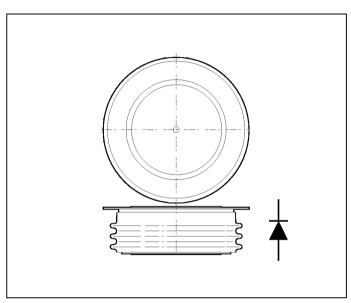
#### **FEATURES**

- Double Side Cooling.
- High Surge Capability.
- Low Recovery Charge.

### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Reverse Voltage V <sub>RRM</sub> V	Conditions
DFB54 35	3500	$V_{RSM} = V_{RRM} + 100V$
DFB54 34	3400	TIOW TITW
DFB54 33	3300	
DFB54 32	3200	
DFB54 31	3100	
DFB54 30	3000	

Lower voltage grades available.



Outline type code: DO200AD.
See package outlines for further information.

## **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units		
Double Side Cooled						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 65°C	2135	Α		
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 65^{\circ}C$	3350	Α		
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 65°C	3060	Α		
Single Side Cooled (Anode side)						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 65°C	1320	Α		
I <sub>F(RMS)</sub>	RMS value	$T_{case} = 65^{\circ}C$	2080	Α		
I <sub>F</sub>	Continuous (direct) forward current	$T_{case} = 65^{\circ}C$	1810	Α		

## DFB54

## **SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10me half cine; with 09/ V T = 150°C	20.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	10ms half sine; with 0% V <sub>RRM.</sub> T <sub>j</sub> = 150°C	2000 x 10 <sup>3</sup>	A²s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10me half cine: with 50% V T = 150°C	16	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	10ms half sine; with 50% V <sub>RRM,</sub> T <sub>j</sub> = 150°C	1280 x 10 <sup>3</sup>	A²s

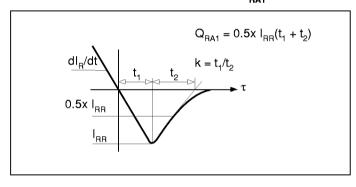
# THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{\text{th(j-c)}}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.013	°C/W
		Single side cooled	Anode dc	-	0.025	°C/W
			Cathode dc	-	0.027	°C/W
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Clamping force 44kN with mounting compound	Double side	-	0.003	°C/W
			Single side	-	0.006	°C/W
T <sub>vj</sub>	Virtual junction temperature	Forward (conducting)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	150	°C
-	Clamping force			39.6	48.4	kN

## **CHARACTERISTICS**

Symbol	Parameter	Conditions	Тур.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 1500A peak, T <sub>case</sub> = 25°C	-	1.7	>
I <sub>RRM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 150°C	-	100	mA
t <sub>rr</sub>	Reverse recovery time		-	6.5	μs
Q <sub>RA1</sub>	Recovered charge (50% chord)	$I_{\rm F} = 1000$ A, di <sub>RR</sub> /dt = 100A/ $\mu$ s	-	1500	μС
I <sub>RM</sub>	Reverse recovery current	$T_{case} = 150$ °C, $V_{R} = 100$ V	-	450	Α
К	Soft factor		-	-	-
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 150°C	-	1.15	٧
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	0.32	mΩ
V <sub>FRM</sub>	Forward recovery voltage	di/dt = 1000A/μs, T <sub>j</sub> = 125°C	-	-	V

# DEFINITION OF K FACTOR AND $\mathbf{Q}_{\text{RA1}}$



## DFB54

## **CURVES**

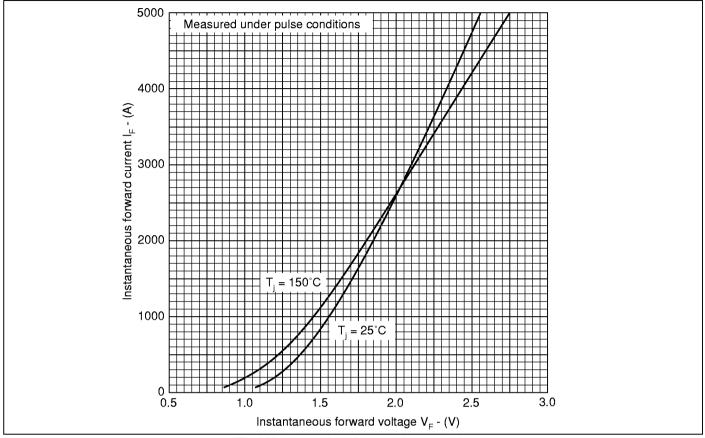


Fig.1 Maximum (limit) forward characteristics

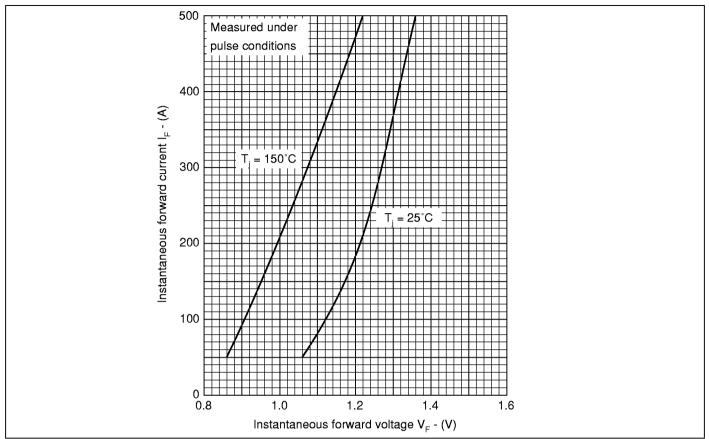


Fig.2 Maximum (limit) forward characteristics

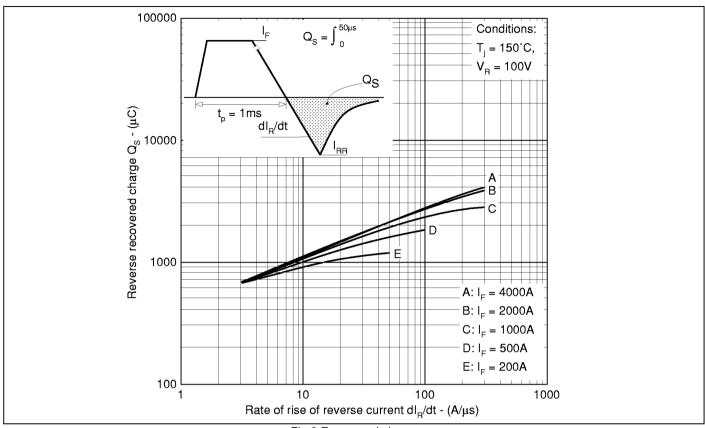


Fig.3 Recovered charge

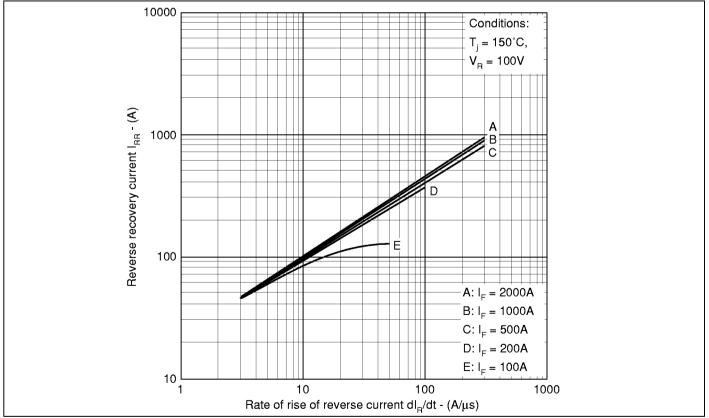


Fig.4 Typical reverse recovery current vs rate of rise of reverse current

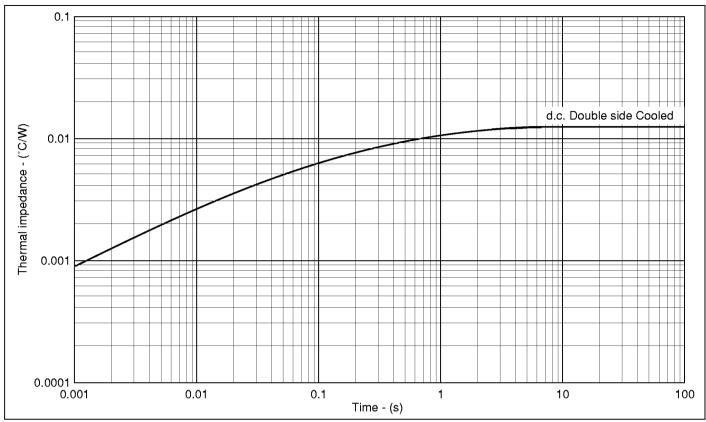
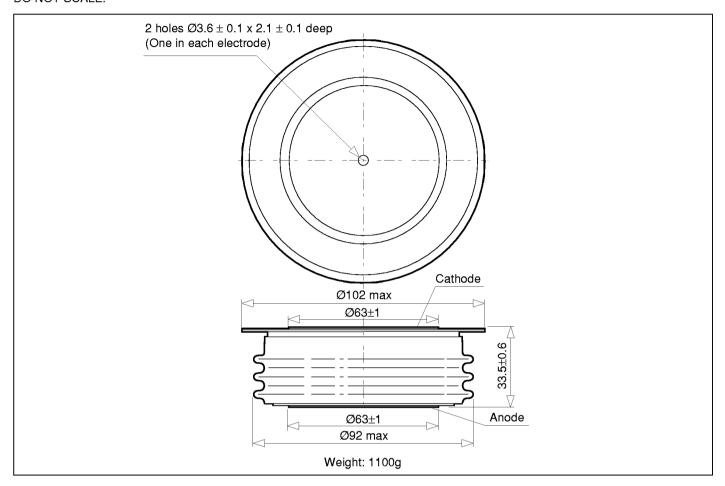


Fig.5 Maximum (limit) transient thermal impedance - junction to case - (°C/W)

#### **DFB54**

#### **PACKAGE DETAILS - DO200AD**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





#### **SEMICONDUCTOR**

HEADQUARTERS OPERATIONS

MITEL SEMICONDUCTOR

Cheney Manor, Swindon, Wiltshire SN2 2QW, United Kingdom.

Tel: (01793) 518000

Fax: (01793) 518411

MITEL SEMICONDUCTOR

1500 Green Hills Road, Scotts Valley, California 95066-4922 United States of America.

Tel (408) 438 2900 Fax: (408) 438 5576/6231 Internet: http://www.gpsemi.com

POWER PRODUCT CUSTOMER SERVICE CENTRES

- FRANCE,BENELUX & SPAIN Les Ulis Cedex Tel: (1) 69 18 90 00 Fax: (1) 64 46 54 50
- GERMANY Munich Tel: (089) 419508-20 Fax: (089) 419508-55
- NORTH AMERICA Dedham, USA Tel: (781) 251 0126 Fax: (781) 251 0106
- UK Lincoln Tel: (01522) 500500 Fax : (01522) 510550

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